# BLC8G27LS-210PV

# **Power LDMOS transistor**

**AMPLEON** 

Rev. 2 — 1 September 2015

Product data sheet

## 1. Product profile

### 1.1 General description

200 W LDMOS power transistor with improved video bandwidth for base station applications at frequencies from 2500 MHz to 2700 MHz.

Table 1. Typical performance

Typical RF performance at  $T_{case}$  = 25 °C in a common source class-AB production test circuit.

Test signal	f	$I_{Dq}$	V <sub>DS</sub>	P <sub>L(AV)</sub>	G <sub>p</sub>	$\eta_D$	ACPR <sub>5M</sub>
	(MHz)	(mA)	(V)	(W)	(dB)	(%)	(dBc)
2-carrier W-CDMA	2600 to 2700	1730	28	65	17	30	-29 <u>[1]</u>

<sup>[1]</sup> Test signal: 3GPP test model 1; 64 DPCH; PAR = 8.4 dB at 0.01 % probability on CCDF per carrier; 5 MHz carrier spacing.

#### 1.2 Features and benefits

- Excellent ruggedness
- High efficiency
- Low thermal resistance providing excellent thermal stability
- Decoupling leads to enable improved video bandwidth performance (150 MHz typical)
- Designed for broadband operation (2500 MHz to 2700 MHz)
- Lower output capacitance for improved performance in Doherty applications
- Designed for low memory effects providing excellent pre-distortability
- Internally matched for ease of use
- Integrated ESD protection
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)

### 1.3 Applications

■ RF power amplifiers for base stations and multi carrier applications in the 2500 MHz to 2700 MHz frequency range

## 2. Pinning information

Table 2. Pinning

Pin	Description	Simplified outline	Graphic symbol
1	drain2	. 0 4	
2	drain1	6 2 1 9	2 ← 6
3	gate1	5	7
4	gate2	7 3 4 8	3—
5	source [1]		4—1-5
6	video decoupling drain1		8 <b></b>    <del></del>
7	n.c.		9
8	n.c.		1
9	video decoupling drain2		aaa-009150

<sup>[1]</sup> Connected to flange.

## 3. Ordering information

Table 3. Ordering information

Type number	Packag	je	
	Name	lame Description	
BLC8G27LS-210PV	-	air cavity plastic earless flanged package; 8 leads	SOT1251-3

## 4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{DS}$	drain-source voltage		-	65	V
$V_{GS}$	gate-source voltage		-0.5	+13	V
T <sub>stg</sub>	storage temperature		-65	+150	°C
Tj	junction temperature	<u>[1]</u>	-	225	°C

<sup>[1]</sup> Continuous use at maximum temperature will affect the reliability, for details refer to the on-line MTF calculator.

## 5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Тур	Unit
R <sub>th(j-c)</sub>	thermal resistance from junction to case	$T_{case}$ = 80 °C; $P_{L}$ = 65 W	0.22	K/W

### 6. Characteristics

Table 6. DC characteristics

 $T_i = 25$  °C per section, unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{(BR)DSS}$	drain-source breakdown voltage	$V_{GS} = 0 \text{ V}; I_D = 1.44 \text{ mA}$	65	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	V <sub>DS</sub> = 10 V; I <sub>D</sub> = 144 mA	1.5	1.9	2.3	V
$V_{GSq}$	gate-source quiescent voltage	V <sub>DS</sub> = 28 V; I <sub>D</sub> = 865 mA	1.6	2	2.4	V
I <sub>DSS</sub>	drain leakage current	V <sub>GS</sub> = 0 V; V <sub>DS</sub> = 28 V	-	-	2.8	μΑ
I <sub>DSX</sub>	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $V_{DS} = 10 \text{ V}$	-	26.9	-	А
I <sub>GSS</sub>	gate leakage current	V <sub>GS</sub> = 11 V; V <sub>DS</sub> = 0 V	-	-	280	nA
g <sub>fs</sub>	forward transconductance	V <sub>DS</sub> = 10 V; I <sub>D</sub> = 7.2 A	-	11.2	-	S
R <sub>DS(on)</sub>	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75 V;$ $I_D = 5.4 A$	-	0.10	-	Ω

#### Table 7. RF characteristics

Test signal: 2-carrier W-CDMA; 3GPP test model 1 with 64 DPCH; PAR = 8.4 dB at 0.01 % probability on the CCDF;  $f_1$  = 2602.5 MHz;  $f_2$  = 2607.5 MHz;  $f_3$  = 2692.5 MHz;  $f_4$  = 2697.5 MHz; RF performance at  $V_{DS}$  = 28 V;  $I_{Dq}$  = 1730 mA;  $T_{case}$  = 25 °C; unless otherwise specified; in a water cooled class-AB test circuit.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Gp	power gain	P <sub>L(AV)</sub> = 65 W	15.8	17	-	dB
$\eta_{D}$	drain efficiency	P <sub>L(AV)</sub> = 65 W	27	30	-	%
RLin	input return loss	P <sub>L(AV)</sub> = 65 W	-	-13	-8	dB
ACPR <sub>5M</sub>	adjacent channel power ratio (5 MHz)	P <sub>L(AV)</sub> = 65 W	-	-29	-26	dBc

## 7. Test information

## 7.1 Ruggedness in class-AB operation

The BLC8G27LS-210PV is capable of withstanding a load mismatch corresponding to VSWR = 10 : 1 through all phases under the following conditions:  $V_{DS}$  = 28 V;  $I_{Dq}$  = 1730 mA;  $P_{L}$  = 200 W (CW); f = 2600 MHz.

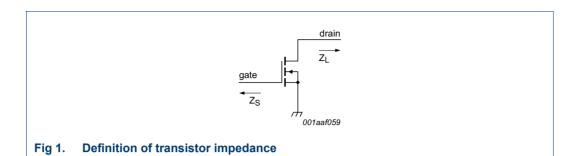
### 7.2 Impedance information

Table 8. Typical impedance

Measured load-pull data per section;  $I_{Dq} = 865 \text{ mA}$ ;  $V_{DS} = 28 \text{ V}$ .

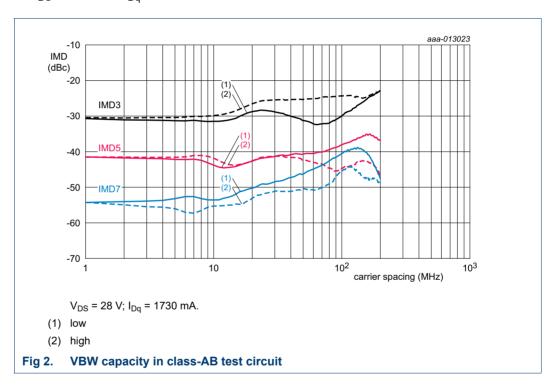
f	Z <sub>S</sub> [1]	Z <sub>L</sub> [1]
(MHz)	(Ω)	(Ω)
2500	2.58 – j5.80	1.60 – j4.32
2600	3.40 – j6.30	1.65 – j4.44
2700	6.35 – j6.45	1.77 – j4.75

[1]  $Z_S$  and  $Z_L$  defined in Figure 1.

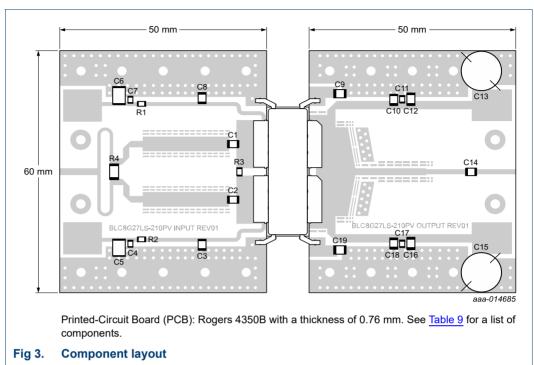


## 7.3 VBW in a class-AB operation

The BLC8G27LS-210PV shows 150 MHz (typical) video bandwidth (IMD third-order intermodulation inflection point) in a class-AB test circuit in the 2.6 GHz to 2.7 GHz band at  $V_{DS}$  = 28 V and  $I_{Dq}$  = 1.73 A.



### 7.4 Test circuit



**Table 9. List of components** See Figure 3 for component layout.

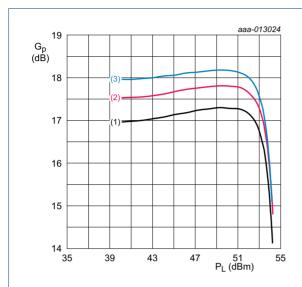
Component	Description	Value	Remarks
C1, C2	multilayer ceramic chip capacitor	1.6 pF [1]	ATC 800B
C3, C8, C10, C14, C18	multilayer ceramic chip capacitor	24 pF [1]	ATC 800B
C4, C7	multilayer ceramic chip capacitor	100 nF [2]	Murata
C5, C6	multilayer ceramic chip capacitor	1 μF <u>[2</u>	Murata
C9, C12, C16, C19	multilayer ceramic chip capacitor	470 μF, 50 V	Murata
C11, C17	multilayer ceramic chip capacitor	220 nF [2	Murata
C13, C15	electrolytic capacitor	> 470 μF, 63 V	
R1, R2	chip resistor	4.7 Ω, 1 % tolerance	SMD 0805
R3	chip resistor	10 Ω, 1 % tolerance	SMD 0805
R4	chip resistor	100 Ω, 1 % tolerance	SMD 2010

<sup>[1]</sup> American Technical Ceramics type 800B or capacitor of same quality.

<sup>[2]</sup> Murata or capacitor of same quality.

### 7.5 Graphical data

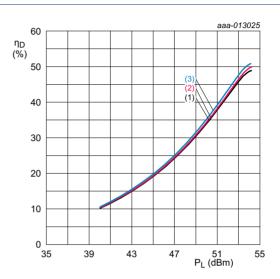
### 7.5.1 Pulsed CW



 $V_{DS}$  = 28 V;  $I_{Dq}$  = 1730 mA;  $t_p$  = 100  $\mu s;$   $\delta$  = 10 %.

- (1) f = 2600 MHz
- (2) f = 2650 MHz
- (3) f = 2700 MHz

Fig 4. Power gain as a function of output power; typical values

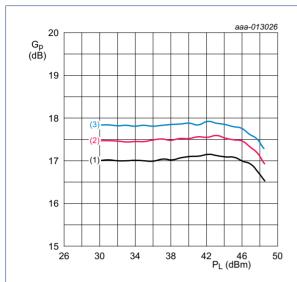


 $V_{DS}$  = 28 V;  $I_{Dq}$  = 1730 mA;  $t_p$  = 100  $\mu s; \, \delta$  = 10 %.

- (1) f = 2600 MHz
- (2) f = 2650 MHz
- (3) f = 2700 MHz

Fig 5. Drain efficiency as a function of out power; typical values

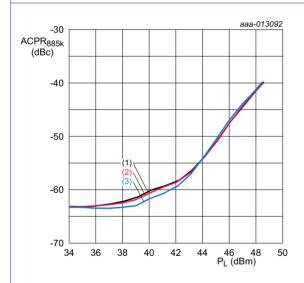
#### 7.5.2 IS-95



 $V_{DS} = 28 \text{ V}; I_{Dq} = 1730 \text{ mA}.$ 

- (1) f = 2605 MHz
- (2) f = 2650 MHz
- (3) f = 2695 MHz

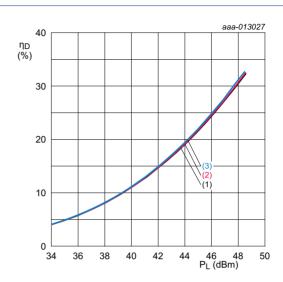
Fig 6. Power gain as a function of output power; typical values



 $V_{DS} = 28 \text{ V}; I_{Dq} = 1730 \text{ mA}.$ 

- (1) f = 2605 MHz
- (2) f = 2650 MHz
- (3) f = 2695 MHz

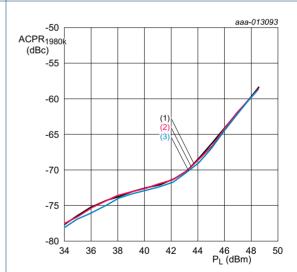
Fig 8. Adjacent channel power ratio (885 kHz) as a function of output power; typical values



 $V_{DS} = 28 \text{ V}; I_{Dq} = 1730 \text{ mA}.$ 

- (1) f = 2605 MHz
- (2) f = 2650 MHz
- (3) f = 2695 MHz

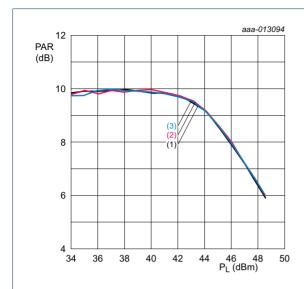
Fig 7. Drain efficiency as a function of output power; typical values



 $V_{DS} = 28 \text{ V}; I_{Dq} = 1730 \text{ mA}.$ 

- (1) f = 2605 MHz
- (2) f = 2650 MHz
- (3) f = 2695 MHz

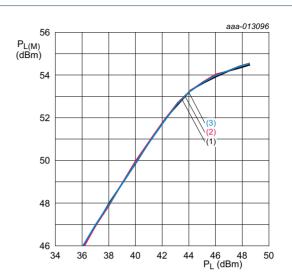
Fig 9. Adjacent channel power ratio (1980 kHz) as a function of output power; typical values



 $V_{DS}$  = 28 V;  $I_{Dq}$  = 1730 mA.

- (1) f = 2605 MHz
- (2) f = 2650 MHz
- (3) f = 2695 MHz

Fig 10. Peak-to-average ratio as a function of output power; typical values

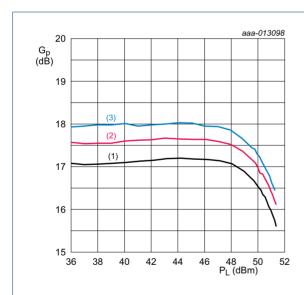


 $V_{DS}$  = 28 V;  $I_{Dq}$  = 1730 mA.

- (1) f = 2605 MHz
- (2) f = 2650 MHz
- (3) f = 2695 MHz

Fig 11. Peak output power as a function of output power; typical values

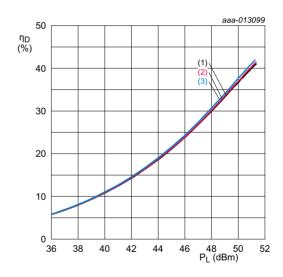
#### 7.5.3 1-Carrier W-CDMA



 $V_{DS}$  = 28 V;  $I_{Dq}$  = 1730 mA.

- (1) f = 2602.5 MHz
- (2) f = 2650 MHz
- (3) f = 2697.5 MHz

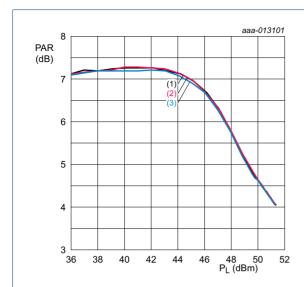
Fig 12. Power gain as a function of output power; typical values



 $V_{DS}$  = 28 V;  $I_{Dq}$  = 1730 mA.

- (1) f = 2602.5 MHz
- (2) f = 2650 MHz
- (3) f = 2697.5 MHz

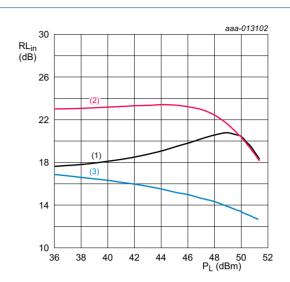
Fig 13. Drain efficiency as a function of output power; typical values



 $V_{DS}$  = 28 V;  $I_{Dq}$  = 1730 mA.

- (1) f = 2602.5 MHz
- (2) f = 2650 MHz
- (3) f = 2697.5 MHz

Fig 14. Peak-to-average ratio as a function of output power; typical values

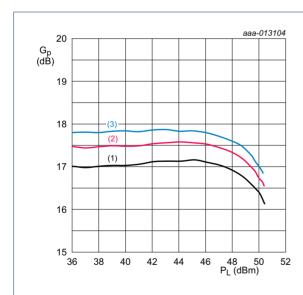


 $V_{DS}$  = 28 V;  $I_{Dq}$  = 1730 mA.

- (1) f = 2602.5 MHz
- (2) f = 2650 MHz
- (3) f = 2697.5 MHz

Fig 15. Input return loss as a function of output power; typical values

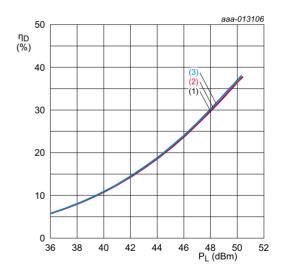
#### 7.5.4 2-Carrier W-CDMA



 $V_{DS}$  = 28 V;  $I_{Dq}$  = 1730 mA.

- (1) f = 2605 MHz
- (2) f = 2650 MHz
- (3) f = 2695 MHz

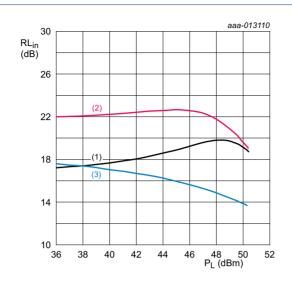
Fig 16. Power gain as a function of output power; typical values



 $V_{DS}$  = 28 V;  $I_{Dq}$  = 1730 mA.

- (1) f = 2605 MHz
- (2) f = 2650 MHz
- (3) f = 2695 MHz

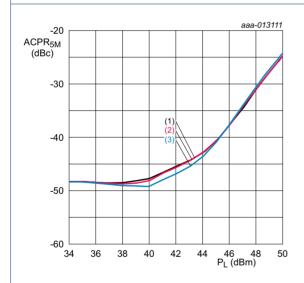
Fig 17. Drain efficiency as a function of output power; typical values



 $V_{DS} = 28 \text{ V}; I_{Dq} = 1730 \text{ mA}.$ 

- (1) f = 2605 MHz
- (2) f = 2650 MHz
- (3) f = 2695 MHz

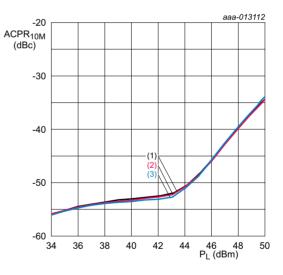
Fig 18. Input return loss as a function of output power; typical values



 $V_{DS} = 28 \text{ V}; I_{Dq} = 1730 \text{ mA}.$ 

- (1) f = 2605 MHz
- (2) f = 2650 MHz
- (3) f = 2695 MHz

Fig 19. Adjacent channel power ratio (5 MHz) as a function of output power; typical values



 $V_{DS}$  = 28 V;  $I_{Dq}$  = 1730 mA.

- (1) f = 2605 MHz
- (2) f = 2650 MHz
- (3) f = 2695 MHz

Fig 20. Adjacent channel power ratio (10 MHz) as a function of output power; typical values

## 8. Package outline

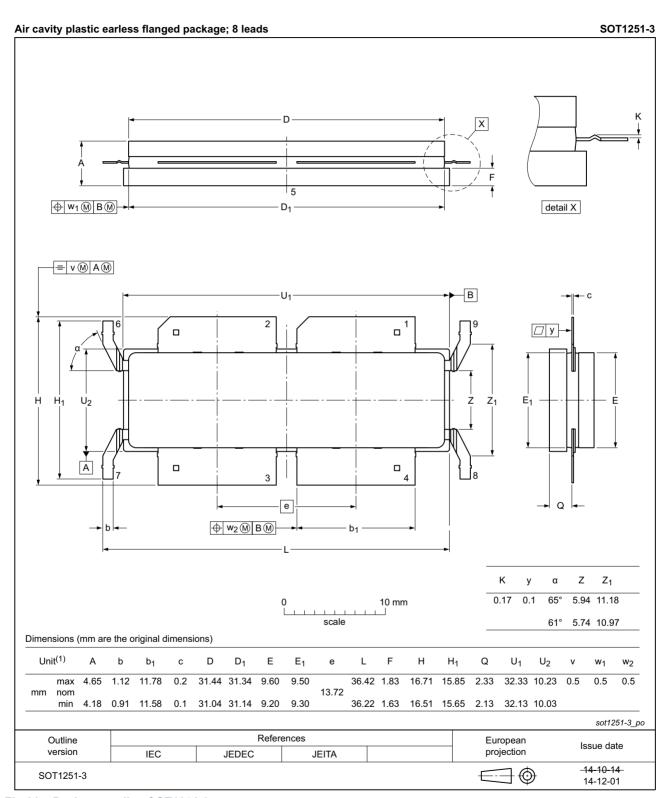


Fig 21. Package outline SOT1251-3

**Product data sheet** 

## 9. Handling information

#### CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the ANSI/ESD S20.20, IEC/ST 61340-5, JESD625-A or equivalent standards.

## 10. Abbreviations

Table 10. Abbreviations

Acronym	Description
3GPP	3rd Generation Partnership Project
CCDF	Complementary Cumulative Distribution Function
CW	Continuous Wave
DPCH	Dedicated Physical CHannel
ESD	ElectroStatic Discharge
IS-95	Interim Standard 95
LDMOS	Laterally Diffused Metal Oxide Semiconductor
MTF	Median Time to Failure
PAR	Peak-to-Average Ratio
SMD	Surface Mounted Device
VBW	Video BandWidth
VSWR	Voltage Standing Wave Ratio
W-CDMA	Wideband Code Division Multiple Access

## 11. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes	
BLC8G27LS-210PV#2	20150901	Product data sheet	-	BLC8G27LS-210PV v.1	
Modifications:	The format of this document has been redesigned to comply with the new identity guidelines of Ampleon.				
	Legal texts have been adapted to the new company name where appropriate.				
BLC8G27LS-210PV v.1	20150209	Product data sheet	-	-	

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Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
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## BLC8G27LS-210PV

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# **AMPLEON**

# BLC8G27LS-210PV

### **Power LDMOS transistor**

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Please be aware that important notices concerning this document and the product(s) described herein, have been included in section 'Legal information'.